Vishay Semiconductors

Insulated Gen 2 Schottky Rectifier Module, 100 A



www.vishay.com

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
$I_{F(AV)}$ per module at $T_C = 93 \ ^{\circ}C$	100 A					
V _R	100 V					
V_{FM} at 50 A, $T_C = 25 \ ^\circ C$	0.83 V					
Package	SOT-227					
Circuit configuration	Two separate diodes, parallel pin-out					

FEATURES

- Max. T_J = 150 °C
- Two fully independent diodes
- Fully insulated package
- Trench MOS Barrier Schottky technology
- Ultra low forward voltage drop
- Optimized for power conversion: welding and industrial SMPS applications
- Easy to use and parallel
- Industry standard outline
- · Designed and qualified for industrial level
- UL approved file E78996
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-QA100FA10 insulated modules integrate two state of the art Trench MOS Schottky technology rectifiers in the compact, industry standard SOT-227 package.

These devices are thus intended for high frequency converters and switching power supplies.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
V _F	I _F = 50 A, T _J = 150 °C	0.66	V			
TJ	Range	-40 to +150	°C			

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C unless otherwise specified)						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage		V _R		100	V	
Average forward current	per module	1	T _C = 93 °C	100		
Average forward current	per diode	I _{F(AV)}	T _C = 93 °C	50		
Continuous forward current	per module	1	T _C = 90 °C	134	A	
	per diode	IF	T _C = 90 °C	67		
Single pulse forward current per diode		I _{FSM}	T_{C} = 150 °C, t = 6 ms, square	450		
Maximum power dissipation per diode		PD	T _C = 90 °C	67	W	
Non-repetitive avalanche energy per diode		E _{AS}	T _J = 25 °C, L = 1 mH	583	mJ	
RMS isolation voltage		VISOL	Any terminal to case, t = 1 min	2500	V	
Operating junction and storage temperatures		T _J , T _{Stg}		-40 to +150	°C	

ELECTRICAL SPECIFICATIONS PER DIODE ($T_J = 25 \text{ °C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 1 mA	100	-	-	
Forward voltage	V _{FM}	I _F = 50 A	-	0.83	1.03	V
		I _F = 50 A, T _J = 150 °C	-	0.66	-	
Reverse leakage current	I _{RM}	V _R = 100 V	-	0.03	0.8	mA
neverse leakage current		T _J = 125 °C, V _R = 100 V	-	17	-	ШA
Junction capacitance	CT	$V_{R} = 100 V, f = 1 MHz$	-	259	-	pF

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COMPLIANT



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THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Junction-to-case, single leg conducting	в		-	-	0.89		
Junction-to-case, both leg conducting	R _{thJC}		-	-	0.45	°C/W	
Case-to-heatsink	R _{thCS}	Flat, greased surface	-	0.1	-		
Weight			-	30	-	g	
Mounting torque		Torque to terminal	-	-	1.1 (9.7)	Nm (lbf.in)	
Mounting torque		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)	
Case style				SC)T-227		

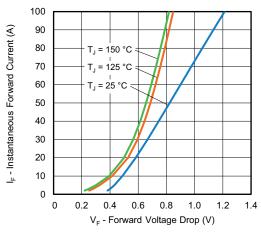


Fig. 1 - Typical Forward Voltage Drop Characteristics

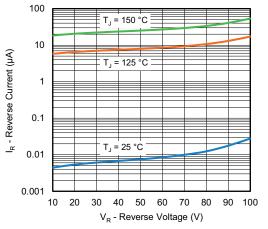


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

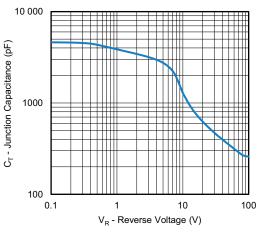
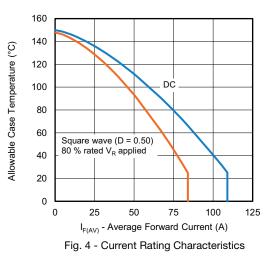


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



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VS-QA100FA10

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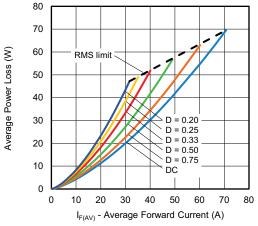


Fig. 5 - Total Power Loss Characteristics

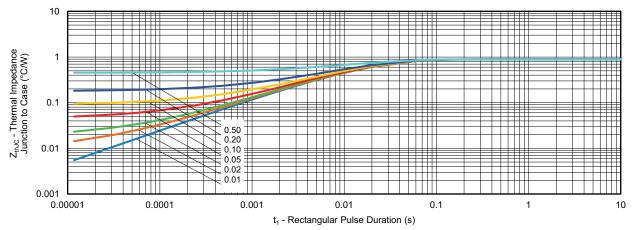
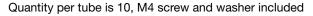


Fig. 6 - Maximum Thermal Impedance ZthJC Characteristics

ORDERING INFORMATION TABLE

Device code	VS-	Q	Α	100	F	Α	10
	1	2	3	4	5	6	7
	1 - 2 -		,	niconduc	'	oduct	
	3 -	Pre	sent sili	con gen	eration		
	4 -	Cur	rent rati	ng (100	= 100 A	A)	
	5 -	Circ	cuit conf	iguratior	n (two s	eparate	diodes
	6 -	Pac	kage in	dicator (SOT-22	27 stand	lard ins
	7 -	Vol	tage rati	ng (10 =	= 100 V))	



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CIRCUIT CONFIGURATION							
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING					
Two separate diodes, parallel pin-out	F	4 0 0 3 4 1 0 0 2 1 2					

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95423					
Part marking information	www.vishay.com/doc?95425				



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